Welcome to E-XFL.COM

Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details	
Product Status	Active
Architecture	MCU, FPGA
Core Processor	Dual ARM® Cortex®-A9 MPCore™ with CoreSight™
Flash Size	-
RAM Size	256KB
Peripherals	DMA
Connectivity	CANbus, EBI/EMI, Ethernet, I²C, MMC/SD/SDIO, SPI, UART/USART, USB OTG
Speed	667MHz
Primary Attributes	Kintex™-7 FPGA, 125K Logic Cells
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	676-BBGA, FCBGA
Supplier Device Package	676-FCBGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc7z030-1ff676i

Table 1: **Absolute Maximum Ratings (1) *(Cont'd)***

Symbol	Description	Min	Max	Units
V_{CCBATT}	Key memory battery backup supply	–0.5	2.0	V
GTX Transceiver				
$V_{MGTAVCC}$	Analog supply voltage for the GTX transmitter and receiver circuits	–0.5	1.1	V
$V_{MGTAVTT}$	Analog supply voltage for the GTX transmitter and receiver termination circuits	–0.5	1.32	V
$V_{MGTVCCAUX}$	Auxiliary analog Quad PLL (QPLL) voltage supply for the GTX transceivers	–0.5	1.935	V
$V_{MGTREFCLK}$	GTX transceiver reference clock absolute input voltage	–0.5	1.32	V
$V_{MGTAVTTRCAL}$	Analog supply voltage for the resistor calibration circuit of the GTX transceiver column	–0.5	1.32	V
V_{IN}	Receiver (RXP/RXN) and Transmitter (TXP/TXN) absolute input voltage	–0.5	1.26	V
I_{DCIN}	DC input current for receiver input pins DC coupled $V_{MGTAVTT}$ = 1.2V	–	14	mA
I_{DCOUT}	DC output current for transmitter pins DC coupled $V_{MGTAVTT}$ = 1.2V	–	14	mA
XADC				
V_{CCADC}	XADC supply relative to GNDADC	–0.5	2.0	V
V_{REFP}	XADC reference input relative to GNDADC	–0.5	2.0	V
Temperature				
T_{STG}	Storage temperature (ambient)	–65	150	°C
T_{SOL}	Maximum soldering temperature for Pb/Sn component bodies (7)	–	+220	°C
	Maximum soldering temperature for Pb-free component bodies (7)	–	+260	°C
T_j	Maximum junction temperature(7)	–	+125	°C

Notes:

1. Stresses beyond those listed under Absolute Maximum Ratings might cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those listed under Operating Conditions is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods of time might affect device reliability.
2. Applies to both MIO supply banks V_{CCO_MIO0} and V_{CCO_MIO1}.
3. The lower absolute voltage specification always applies.
4. For I/O operation, refer to UG471: *7 Series FPGAs SelectIO Resources User Guide* or UG585, *Zynq-7000 All Programmable SoC Technical Reference Manual*.
5. The maximum limit applied to DC signals.
6. For maximum undershoot and overshoot AC specifications, see Table 4 and Table 5.
7. For soldering guidelines and thermal considerations, see UG865, *Zynq-7000 All Programmable SoC Packaging and Pinout Specification*.

Table 2: **Recommended Operating Conditions (1)(2)**

Symbol	Description	Min	Typ	Max	Units
PS					
V_{CCPINT}(3)	PS internal supply voltage	0.95	1.00	1.05	V
V_{CCPAUX}	PS auxiliary supply voltage	1.71	1.80	1.89	V
V_{CCPLL}	PS PLL supply voltage	1.71	1.80	1.89	V
V_{CCO_DDR}	PS DDR supply voltage	1.14		1.89	V
V_{CCO_MIO}(4)	PS supply voltage for MIO banks	1.71	–	3.465	V
V_{PIN}(5)	PS DDR and MIO I/O input voltage	–0.20	–	V_{CCO_DDR} + 0.20 V_{CCO_MIO} + 0.20	V
	PS DDR and MIO I/O input voltage for V_{REF} and differential I/O standards	–0.20	–	2.625	V

Table 2: **Recommended Operating Conditions (1)(2) *(Cont'd)***

Symbol	Description	Min	Typ	Max	Units
PL					
V_{CCINT}	Internal supply voltage	0.97	1.00	1.03	V
V_{CCAUX}	Auxiliary supply voltage	1.71	1.80	1.89	V
V_{CCBRAM}	Block RAM supply voltage	0.97	1.00	1.03	V
V_{CCO}(6)(7)	Supply voltage for 3.3V HR I/O banks	1.14	–	3.465	V
	Supply voltage for 1.8V HP I/O banks	1.14	–	1.89	V
V_{CCAUX_IO}	Auxiliary supply voltage when set to 1.8V	1.71	1.80	1.89	V
	Auxiliary supply voltage when set to 2.0V	1.94	2.00	2.06	V
V_{IN}(5)	I/O input voltage	–0.20	–	V_{CCO} + 0.20	V
	I/O input voltage for V_{REF} and differential I/O standards	–0.20	–	2.625	
I_{IN}(8)	Maximum current through any (PS or PL) pin in a powered or unpowered bank when forward biasing the clamp diode	–	–	10	mA
V_{CCBATT}(9)	Battery voltage	1.0	–	1.89	V
GTX Transceiver					
$V_{MGTAVCC}$(10)	Analog supply voltage for the GTX transceiver QPLL frequency range ≤ 10.3125 GHz(11)(12)	0.97	1.0	1.08	V
	Analog supply voltage for the GTX transceiver QPLL frequency range > 10.3125 GHz	1.02	1.05	1.08	
$V_{MGTAVTT}$(10)	Analog supply voltage for the GTX transmitter and receiver termination circuits	1.17	1.2	1.23	V
$V_{MGTVCCAUX}$(10)	Auxiliary analog QPLL voltage supply for the transceivers	1.75	1.80	1.85	V
$V_{MGTAVTTRCAL}$(10)	Analog supply voltage for the resistor calibration circuit of the GTX transceiver column	1.17	1.2	1.23	V
XADC					
V_{CCADC}	XADC supply relative to GNDADC	1.71	1.80	1.89	V
V_{REFP}	Externally supplied reference voltage	1.20	1.25	1.30	V
Temperature					
T_j	Junction temperature operating range for commercial (C) temperature devices	0	–	85	°C
	Junction temperature operating range for extended (E) temperature devices	0	–	100	°C
	Junction temperature operating range for industrial (I) temperature devices	–40	–	100	°C

Notes:

1. All voltages are relative to ground. The PL and PS share a common ground.
2. For the design of the power distribution system consult UG933, *Zynq-7000 All Programmable SoC PCB Design and Pin Planning Guide*.
3. When the processor cores operate $F_{CPU\_6X4X\_621\_MAX}$ at 1 GHz (-3E speed grade), the V_{CCPINT} minimum is 0.97V and the V_{CCPINT} maximum is 1.03V.
4. Applies to both MIO supply banks V_{CCO_MIO0} and V_{CCO_MIO1}.
5. The lower absolute voltage specification always applies.
6. Configuration data is retained even if V_{CCO} drops to 0V.
7. Includes V_{CCO} of 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V.
8. A total of 200 mA per PS or PL bank should not be exceeded.
9. V_{CCBATT} is required only when using bitstream encryption. If battery is not used, connect V_{CCBATT} to either ground or V_{CCAUX}.
10. Each voltage listed requires the filter circuit described in UG476: *7 Series FPGAs GTX/GTH Transceivers User Guide*.
11. For data rates ≤ 10.3125 Gb/s, $V_{MGTAVCC}$ should be 1.0V ±3% for lower power consumption.
12. For lower power consumption, $V_{MGTAVCC}$ should be 1.0V ±3% over the entire CPLL frequency range.

Table 26: **DDR3L Interface Switching Characteristics (800 Mb/s)(1)**

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
T_{DQDS}(2)	Output DQ to DQS skew	321	–	ps
T_{DQDH}(3)	Output DQS to DQ skew	380	–	ps
T_{DQSS}	Output clock to DQS skew	–0.12	0.04	T_{CK}
T_{CACK}(4)	Command/address output setup time with respect to CLK	636	–	ps
T_{CKCA}(5)	Command/address output hold time with respect to CLK	853	–	ps

Notes:

1. Recommended V_{CCO_DDR} = 1.35V ±5%.
2. Measurement is taken from either the rising edge of DQ that crosses V_{IH}(AC) or the falling edge of DQ that crosses V_{IL}(AC) to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses V_{IL}(DC) or the falling edge of DQ that crosses V_{IH}(DC) to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IH}(AC) or the falling edge of CMD/ADDR that crosses V_{IL}(AC) to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IL}(DC) or the falling edge of CMD/ADDR that crosses V_{IH}(DC) to V_{REF} of CLK.

Table 27: **LPDDR2 Interface Switching Characteristics (800 Mb/s)(1)**

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
T_{DQDS}(2)	Output DQ to DQS skew	111	–	ps
T_{DQDH}(3)	Output DQS to DQ skew	318	–	ps
T_{DQSS}	Output clock to DQS skew	0.91	1.10	T_{CK}
T_{CACK}(4)	Command/address output setup time with respect to CLK	132	–	ps
T_{CKCA}(5)	Command/address output hold time with respect to CLK	363	–	ps

Notes:

1. Recommended V_{CCO_DDR} = 1.2V ±5%.
2. Measurement is taken from either the rising edge of DQ that crosses V_{IH}(AC) or the falling edge of DQ that crosses V_{IL}(AC) to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses V_{IL}(DC) or the falling edge of DQ that crosses V_{IH}(DC) to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IH}(AC) or the falling edge of CMD/ADDR that crosses V_{IL}(AC) to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IL}(DC) or the falling edge of CMD/ADDR that crosses V_{IH}(DC) to V_{REF} of CLK.

Table 28: **LPDDR2 Interface Switching Characteristics (400 Mb/s)(1)**

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
T_{DQDS}(2)	Output DQ to DQS skew	561	–	ps
T_{DQDH}(3)	Output DQS to DQ skew	852	–	ps
T_{DQSS}	Output clock to DQS skew	0.91	1.08	T_{CK}
T_{CACK}(4)	Command/address output setup time with respect to CLK	617	–	ps
T_{CKCA}(5)	Command/address output hold time with respect to CLK	918	–	ps

Notes:

1. Recommended V_{CCO_DDR} = 1.2V ±5%.
2. Measurement is taken from either the rising edge of DQ that crosses V_{IH}(AC) or the falling edge of DQ that crosses V_{IL}(AC) to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses V_{IL}(DC) or the falling edge of DQ that crosses V_{IH}(DC) to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IH}(AC) or the falling edge of CMD/ADDR that crosses V_{IL}(AC) to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IL}(DC) or the falling edge of CMD/ADDR that crosses V_{IH}(DC) to V_{REF} of CLK.

Table 29: **DDR2 Interface Switching Characteristics (800 Mb/s)(1)**

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
T_{DQDS}(2)	Output DQ to DQS skew	147	–	ps
T_{DQDH}(3)	Output DQS to DQ skew	376	–	ps
T_{DQSS}	Output clock to DQS skew	–0.07	0.08	T_{CK}
T_{CACK}(4)	Command/address output setup time with respect to CLK	732	–	ps
T_{CKCA}(5)	Command/address output hold time with respect to CLK	938	–	ps

Notes:

1. Recommended V_{CCO_DDR} = 1.8V ±5%.
2. Measurement is taken from either the rising edge of DQ that crosses V_{IH}(AC) or the falling edge of DQ that crosses V_{IL}(AC) to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses V_{IL}(DC) or the falling edge of DQ that crosses V_{IH}(DC) to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IH}(AC) or the falling edge of CMD/ADDR that crosses V_{IL}(AC) to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IL}(DC) or the falling edge of CMD/ADDR that crosses V_{IH}(DC) to V_{REF} of CLK.

Static Memory Controller

Table 31: **SMC Interface Delay Characteristics(1)(2)**

Symbol	Description	Min	Max	Units
$T_{NANDDOUT}$	NAND_IO output delay from last register to pad	4.12	6.45	ns
$T_{NANDALE}$	NAND_ALE output delay from last register to pad	5.08	6.33	ns
$T_{NANDCLE}$	NAND_CLE output delay from last register to pad	4.87	6.40	ns
T_{NANDWE}	NAND_WE_B output delay from last register to pad	4.69	5.89	ns
T_{NANDRE}	NAND_RE_B output delay from last register to pad	5.12	6.44	ns
T_{NANDCE}	NAND_CE_B output delay from last register to pad	4.68	5.89	ns
$T_{NANDDIN}$	NAND_IO setup time and input delay from pad to first register	1.48	3.09	ns
$T_{NANDBUSY}$	NAND_BUSY setup time and input delay from pad to first register	2.48	3.33	ns
T_{SRAMA}	SRAM_A output delay from last register to pad	3.94	5.73	ns
$T_{SRAMDOUT}$	SRAM_DQ output delay from last register to pad	4.66	6.45	ns
T_{SRAMCE}	SRAM_CE output delay from last register to pad	4.57	5.95	ns
T_{SRAMOE}	SRAM_OE_B output delay from last register to pad	4.79	6.13	ns
$T_{SRAMBLS}$	SRAM_BLS_B output delay from last register to pad	5.25	6.74	ns
T_{SRAMWE}	SRAM_WE_B output delay from last register to pad	5.12	6.48	ns
$T_{SRAMDIN}$	SRAM_DQ setup time and input delay from pad to first register	1.93	3.05	ns
$T_{SRAMWAIT}$	SRAM_WAIT setup time and input delay from pad to first register	2.26	3.15	ns

Notes:

1. All parameters do not include the package flight time and register controlled delays.
2. Refer to the ARM® PrimeCell® Static Memory Controller (PL350 series) Technical Reference Manual for more SMC timing details.

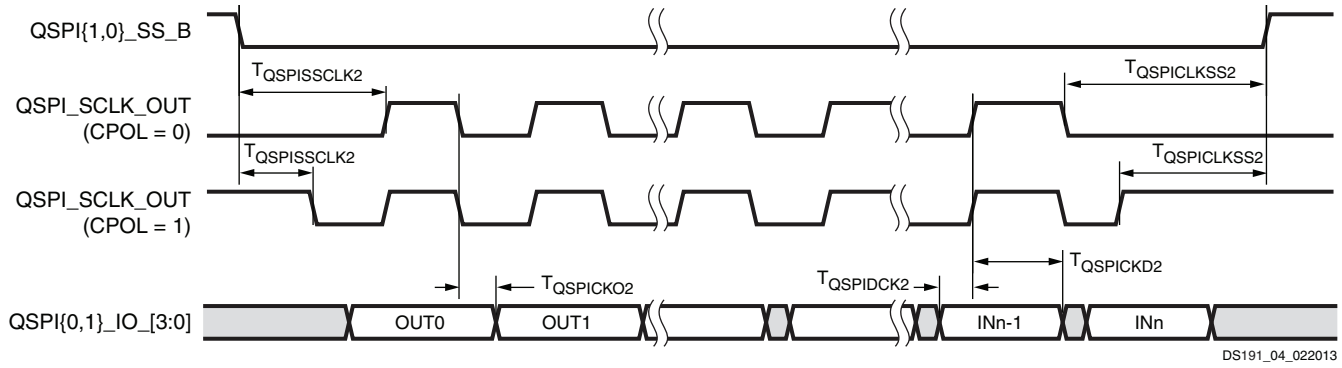

Figure 4: **Quad-SPI Interface (Feedback Clock Disabled) Timing Diagram**

ULPI Interfaces

Table 33: **ULPI Interface Clock Receiving Mode Switching Characteristics**(1)(2)

Symbol	Description	Min	Typ	Max	Units
$T_{ULPIDCK}$	Input setup to ULPI clock, all inputs	3.00	–	–	ns
$T_{ULPICKD}$	Input hold to ULPI clock, all inputs	1.00	–	–	ns
$T_{ULPICKO}$	ULPI clock to output valid, all outputs	1.70	–	8.86	ns
$F_{ULPICLK}$	ULPI device clock frequency	–	60	–	MHz

Notes:

1. Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads, 60 MHz device clock frequency.
2. All timing values assume an ideal external input clock. Actual design system timing budgets should account for additional external clock jitter.

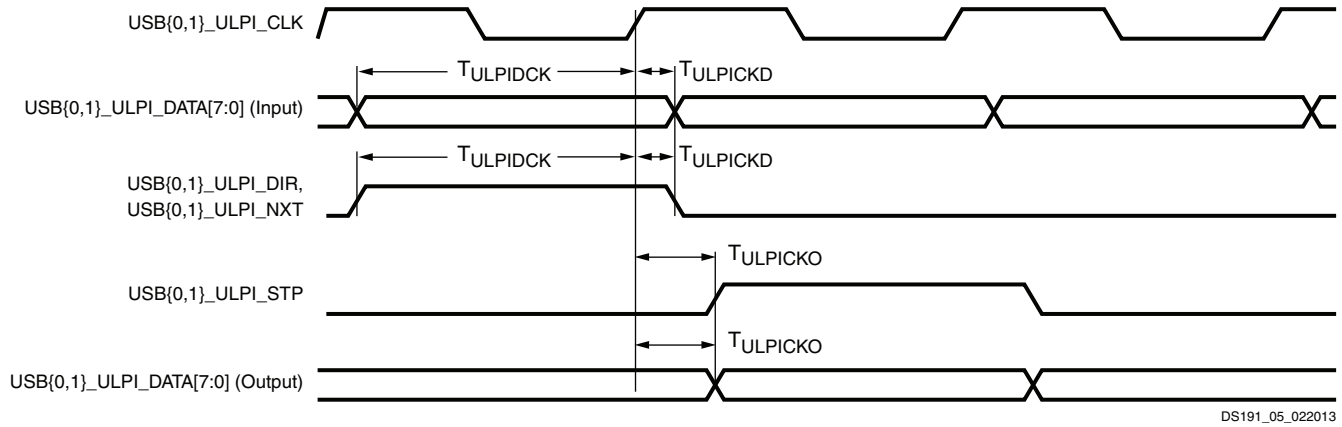

Figure 5: **ULPI Interface Timing Diagram**

I2C Interfaces

Table 37: **I2C Fast Mode Interface Switching Characteristics(1)**

Symbol	Description	Min	Typ	Max	Units
$T_{DCI2CFCLK}$	I2C{0,1}SCL duty cycle	–	50	–	%
$T_{I2CFCKO}$	I2C{0,1}SDAO clock to out delay	–	–	900	ns
$T_{I2CFDCK}$	I2C{0,1}SDAI setup time	100	–	–	ns
$F_{I2CFCLK}$	I2C{0,1}SCL clock frequency	–	–	400	KHz

Notes:

1. Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

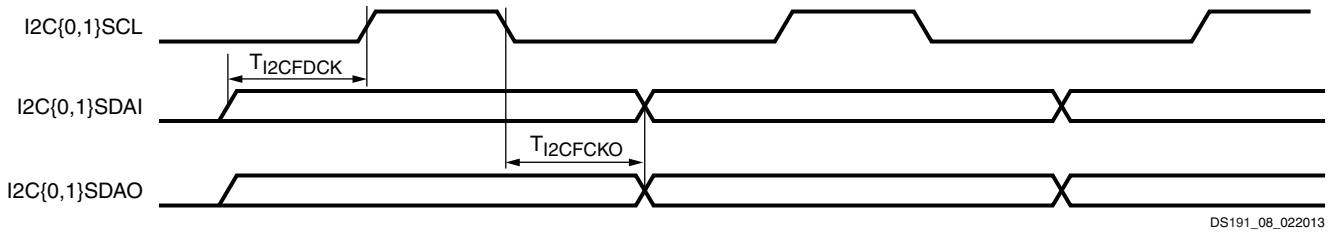

Figure 9: **I2C Fast Mode Interface Timing Diagram**

Table 38: **I2C Standard Mode Interface Switching Characteristics(1)**

Symbol	Description	Min	Typ	Max	Units
$T_{DCI2CSCLK}$	I2C{0,1}SCL duty cycle	–	50	–	%
$T_{I2CSCKO}$	I2C{0,1}SDAO clock to out delay	–	–	3450	ns
$T_{I2CSDCK}$	I2C{0,1}SDAI setup time	250	–	–	ns
$F_{I2CSCLK}$	I2C{0,1}SCL clock frequency	–	–	100	KHz

Notes:

1. Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

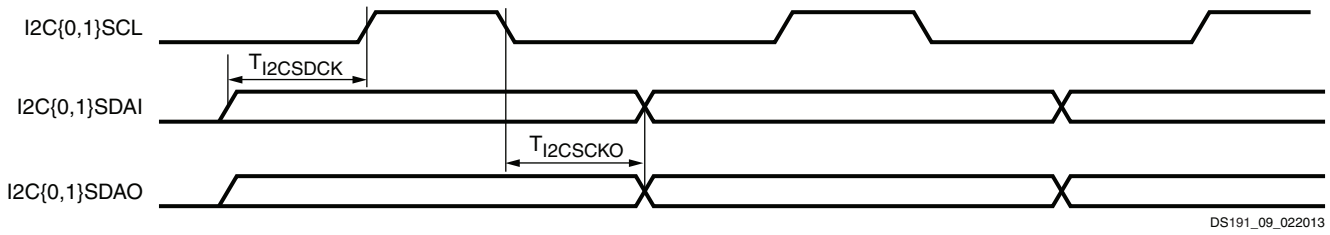

Figure 10: **I2C Standard Mode Interface Timing Diagram**

SPI Interfaces

Table 39: **SPI Master Mode Interface Switching Characteristics(1)**

Symbol	Description	Min	Typ	Max	Units
$T_{DCMSPICLK}$	SPI master mode clock duty cycle	–	50	–	%
$T_{MSPIDCK}$	Input setup time for SPI{0,1}_MISO	2.00	–	–	ns
$T_{MSPICKD}$	Input hold time for SPI{0,1}_MISO	8.20	–	–	ns
$T_{MSPICKO}$	Output delay for SPI{0,1}_MOSI and SPI{0,1}_SS	–3.10	–	3.90	ns
$T_{MSPISSCLK}$	Slave select asserted to first active clock edge	1	–	–	$F_{SPI\_REF\_CLK}$ cycles
$T_{MSPICLKSS}$	Last active clock edge to slave select deasserted	0.5	–	–	$F_{SPI\_REF\_CLK}$ cycles
$F_{MSPICLK}$	SPI master mode device clock frequency	–	–	50.00	MHz
$F_{SPI\_REF\_CLK}$	SPI reference clock frequency	–	–	200.00	MHz

Notes:

1. Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads.

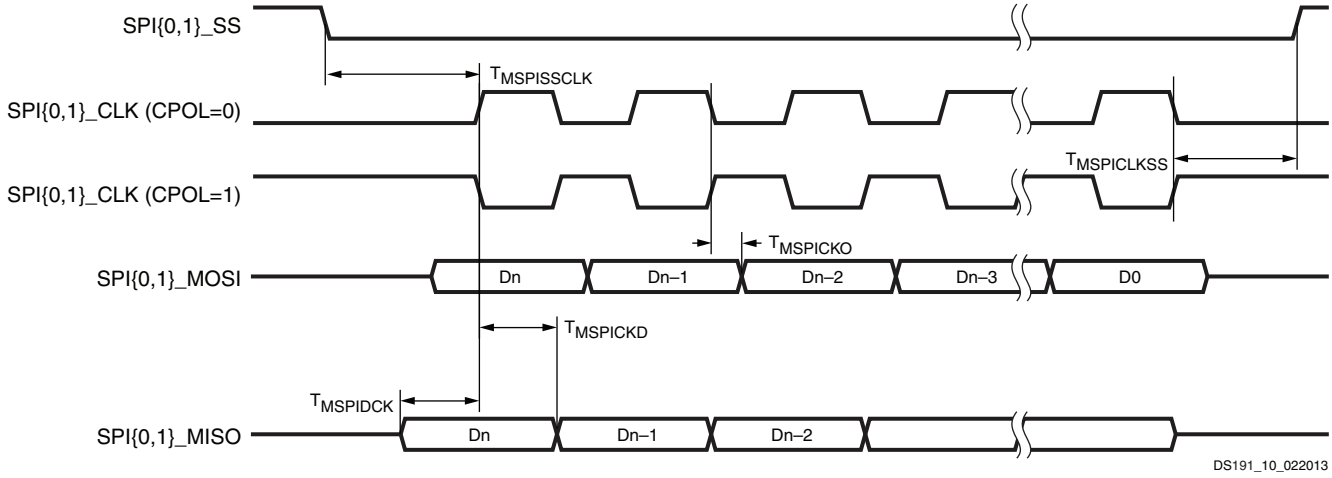

Figure 11: **SPI Master (CPHA = 0) Interface Timing Diagram**

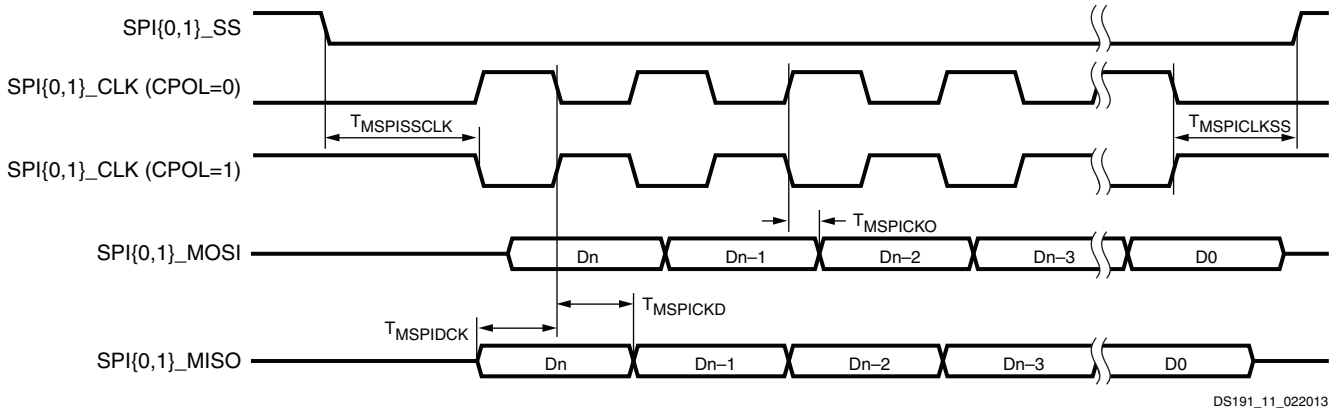

Figure 12: **SPI Master (CPHA = 1) Interface Timing Diagram**

Table 50: **Maximum Physical Interface (PHY) Rate for Memory Interfaces IP available with the Memory Interface Generator (FFG Packages)(1)(2)**

Memory Standard	I/O Bank Type	V_{CCAUX_IO}	Speed Grade			Units
			-3	-2	-1	
4:1 Memory Controllers						
DDR3	HP	2.0V	1866	1866	1600	Mb/s
	HP	1.8V	1600	1333	1066	Mb/s
	HR	N/A	1066	1066	800	Mb/s
DDR3L	HP	2.0V	1600	1600	1333	Mb/s
	HP	1.8V	1333	1066	800	Mb/s
	HR	N/A	800	800	667	Mb/s
DDR2	HP	2.0V	800	800	800	Mb/s
	HP	1.8V	800	800	800	Mb/s
	HR	N/A	800	800	800	Mb/s
RLDRAM III	HP	2.0V	800	667	667	MHz
	HP	1.8V	550	500	450	MHz
	HR	N/A	N/A			
2:1 Memory Controllers						
DDR3	HP	2.0V	1066	1066	800	Mb/s
	HP	1.8V	1066	1066	800	Mb/s
	HR	N/A	1066	1066	800	Mb/s
DDR3L	HP	2.0V	1066	1066	800	Mb/s
	HP	1.8V	1066	1066	800	Mb/s
	HR	N/A	800	800	667	Mb/s
DDR2	HP	2.0V	800	800	800	Mb/s
	HP	1.8V				
	HR	N/A				
QDR II+(3)	HP	2.0V	550	500	450	MHz
	HP	1.8V				
	HR	N/A	500	450	400	MHz
RLDRAM II	HP	2.0V	533	500	450	MHz
	HP	1.8V				
	HR	N/A				
LPDDR2	HP	2.0V	667	667	667	Mb/s
	HP	1.8V	667	667	667	Mb/s
	HR	N/A	667	667	667	Mb/s

Notes:

1. V_{REF} tracking is required. For more information, see UG586, *7 Series FPGAs Memory Interface Solutions User Guide*.
2. When using the internal V_{REF}, the maximum data rate is 800 Mb/s (400 MHz).
3. The maximum QDRII+ performance specifications are for burst-length 4 (BL = 4) implementations. Burst length 2 (BL = 2) implementations are limited to 333 MHz for all speed grades and I/O bank types.

Table 52: **3.3V IOB High Range (HR) Switching Characteristics *(Cont'd)***

I/O Standard	T_{IOPI}			T_{IOOP}			T_{IOTP}			Units
	Speed Grade			Speed Grade			Speed Grade			
	-3	-2	-1	-3	-2	-1	-3	-2	-1	
DIFF_HSTL_II_18_S	0.65	0.69	0.78	1.14	1.23	1.26	1.90	2.09	2.25	ns
HSTL_I_F	0.61	0.64	0.73	1.10	1.19	1.23	1.86	2.05	2.22	ns
HSTL_II_F	0.61	0.64	0.73	1.05	1.18	1.28	1.81	2.04	2.27	ns
HSTL_I_18_F	0.64	0.67	0.76	1.05	1.18	1.28	1.81	2.04	2.27	ns
HSTL_II_18_F	0.64	0.67	0.76	1.03	1.14	1.23	1.79	2.00	2.22	ns
DIFF_HSTL_I_F	0.63	0.67	0.77	1.09	1.18	1.22	1.85	2.04	2.21	ns
DIFF_HSTL_II_F	0.63	0.67	0.77	1.02	1.11	1.14	1.78	1.97	2.13	ns
DIFF_HSTL_I_18_F	0.65	0.69	0.78	1.08	1.17	1.21	1.84	2.03	2.20	ns
DIFF_HSTL_II_18_F	0.65	0.69	0.78	1.01	1.10	1.13	1.77	1.96	2.12	ns
LVCMOS33_S4	1.31	1.40	1.60	3.77	3.90	4.00	4.53	4.76	4.99	ns
LVCMOS33_S8	1.31	1.40	1.60	3.49	3.62	3.72	4.25	4.48	4.71	ns
LVCMOS33_S12	1.31	1.40	1.60	3.05	3.18	3.28	3.81	4.04	4.27	ns
LVCMOS33_S16	1.31	1.40	1.60	3.06	3.43	3.88	3.82	4.29	4.87	ns
LVCMOS33_F4	1.31	1.40	1.60	3.22	3.36	3.45	3.98	4.22	4.44	ns
LVCMOS33_F8	1.31	1.40	1.60	2.71	2.84	2.93	3.47	3.70	3.92	ns
LVCMOS33_F12	1.31	1.40	1.60	2.57	2.85	3.15	3.33	3.71	4.14	ns
LVCMOS33_F16	1.31	1.40	1.60	2.44	2.69	2.96	3.20	3.55	3.95	ns
LVCMOS25_S4	1.08	1.16	1.32	3.08	3.22	3.31	3.84	4.08	4.30	ns
LVCMOS25_S8	1.08	1.16	1.32	2.85	2.98	3.07	3.61	3.84	4.06	ns
LVCMOS25_S12	1.08	1.16	1.32	2.44	2.57	2.67	3.20	3.43	3.66	ns
LVCMOS25_S16	1.08	1.16	1.32	2.79	2.92	3.01	3.55	3.78	4.00	ns
LVCMOS25_F4	1.08	1.16	1.32	2.71	2.84	2.93	3.47	3.70	3.92	ns
LVCMOS25_F8	1.08	1.16	1.32	2.14	2.28	2.37	2.90	3.14	3.36	ns
LVCMOS25_F12	1.08	1.16	1.32	2.15	2.29	2.52	2.91	3.15	3.51	ns
LVCMOS25_F16	1.08	1.16	1.32	1.92	2.17	2.45	2.68	3.03	3.44	ns
LVCMOS18_S4	0.64	0.66	0.74	1.55	1.68	1.78	2.31	2.54	2.77	ns
LVCMOS18_S8	0.64	0.66	0.74	2.14	2.28	2.37	2.90	3.14	3.36	ns
LVCMOS18_S12	0.64	0.66	0.74	2.14	2.28	2.37	2.90	3.14	3.36	ns
LVCMOS18_S16	0.64	0.66	0.74	1.49	1.62	1.72	2.25	2.48	2.71	ns
LVCMOS18_S24(1)	0.64	0.66	0.74	1.74	1.92	2.08	2.50	2.78	3.07	ns
LVCMOS18_F4	0.64	0.66	0.74	1.38	1.51	1.61	2.14	2.37	2.60	ns
LVCMOS18_F8	0.64	0.66	0.74	1.64	1.78	1.87	2.40	2.64	2.86	ns
LVCMOS18_F12	0.64	0.66	0.74	1.64	1.78	1.87	2.40	2.64	2.86	ns
LVCMOS18_F16	0.64	0.66	0.74	1.52	1.68	1.81	2.28	2.54	2.80	ns
LVCMOS18_F24(1)	0.64	0.66	0.74	1.34	1.46	1.55	2.10	2.32	2.54	ns
LVCMOS15_S4	0.66	0.69	0.81	1.86	2.00	2.09	2.62	2.86	3.08	ns
LVCMOS15_S8	0.66	0.69	0.81	2.05	2.18	2.28	2.81	3.04	3.27	ns
LVCMOS15_S12	0.66	0.69	0.81	1.83	2.03	2.23	2.59	2.89	3.22	ns

Table 53: **1.8V IOB High Performance (HP) Switching Characteristics *(Cont'd)***

I/O Standard	T_{IOPI}			T_{IOOP}			T_{IOTP}			Units
	Speed Grade			Speed Grade			Speed Grade			
	-3	-2	-1	-3	-2	-1	-3	-2	-1	
DIFF_HSTL_I_18_F	0.75	0.79	0.92	1.04	1.16	1.24	1.68	1.91	2.06	ns
DIFF_HSTL_II_18_F	0.75	0.79	0.92	0.98	1.09	1.16	1.62	1.85	1.98	ns
DIFF_HSTL_I_DCI_18_F	0.75	0.79	0.92	1.04	1.16	1.24	1.67	1.91	2.06	ns
DIFF_HSTL_II_DCI_18_F	0.75	0.79	0.92	0.98	1.09	1.16	1.61	1.85	1.98	ns
DIFF_HSTL_II _T_DCI_18_F	0.75	0.79	0.92	1.04	1.16	1.24	1.67	1.91	2.06	ns
LVCMOS18_S2	0.47	0.50	0.60	3.95	4.28	4.85	4.59	5.04	5.67	ns
LVCMOS18_S4	0.47	0.50	0.60	2.67	2.98	3.43	3.31	3.73	4.26	ns
LVCMOS18_S6	0.47	0.50	0.60	2.14	2.38	2.72	2.77	3.14	3.54	ns
LVCMOS18_S8	0.47	0.50	0.60	1.98	2.21	2.52	2.61	2.97	3.35	ns
LVCMOS18_S12	0.47	0.50	0.60	1.70	1.91	2.17	2.34	2.67	2.99	ns
LVCMOS18_S16	0.47	0.50	0.60	1.57	1.75	1.97	2.20	2.51	2.79	ns
LVCMOS18_F2	0.47	0.50	0.60	3.50	3.87	4.48	4.14	4.63	5.30	ns
LVCMOS18_F4	0.47	0.50	0.60	2.23	2.50	2.87	2.87	3.25	3.69	ns
LVCMOS18_F6	0.47	0.50	0.60	1.80	2.00	2.26	2.43	2.76	3.08	ns
LVCMOS18_F8	0.47	0.50	0.60	1.46	1.72	2.04	2.10	2.47	2.86	ns
LVCMOS18_F12	0.47	0.50	0.60	1.26	1.40	1.53	1.89	2.16	2.35	ns
LVCMOS18_F16	0.47	0.50	0.60	1.19	1.33	1.44	1.83	2.08	2.26	ns
LVCMOS15_S2	0.59	0.62	0.73	3.55	3.89	4.45	4.19	4.65	5.27	ns
LVCMOS15_S4	0.59	0.62	0.73	2.45	2.70	3.06	3.08	3.45	3.89	ns
LVCMOS15_S6	0.59	0.62	0.73	2.24	2.51	2.88	2.88	3.26	3.71	ns
LVCMOS15_S8	0.59	0.62	0.73	1.91	2.16	2.49	2.55	2.91	3.31	ns
LVCMOS15_S12	0.59	0.62	0.73	1.77	1.98	2.23	2.41	2.73	3.05	ns
LVCMOS15_S16	0.59	0.62	0.73	1.62	1.81	2.02	2.26	2.56	2.84	ns
LVCMOS15_F2	0.59	0.62	0.73	3.38	3.69	4.18	4.02	4.44	5.00	ns
LVCMOS15_F4	0.59	0.62	0.73	2.04	2.21	2.44	2.68	2.97	3.26	ns
LVCMOS15_F6	0.59	0.62	0.73	1.47	1.74	2.09	2.10	2.50	2.91	ns
LVCMOS15_F8	0.59	0.62	0.73	1.31	1.46	1.61	1.95	2.22	2.43	ns
LVCMOS15_F12	0.59	0.62	0.73	1.21	1.34	1.45	1.84	2.10	2.27	ns
LVCMOS15_F16	0.59	0.62	0.73	1.18	1.31	1.41	1.82	2.07	2.23	ns
LVCMOS12_S2	0.64	0.67	0.78	3.38	3.80	4.48	4.02	4.55	5.30	ns
LVCMOS12_S4	0.64	0.67	0.78	2.62	2.94	3.43	3.26	3.70	4.25	ns
LVCMOS12_S6	0.64	0.67	0.78	2.05	2.33	2.72	2.69	3.08	3.54	ns
LVCMOS12_S8	0.64	0.67	0.78	1.94	2.18	2.51	2.58	2.94	3.33	ns
LVCMOS12_F2	0.64	0.67	0.78	2.84	3.15	3.62	3.48	3.90	4.44	ns
LVCMOS12_F4	0.64	0.67	0.78	1.97	2.18	2.44	2.61	2.93	3.26	ns
LVCMOS12_F6	0.64	0.67	0.78	1.33	1.51	1.70	1.96	2.26	2.52	ns
LVCMOS12_F8	0.64	0.67	0.78	1.27	1.42	1.55	1.91	2.18	2.37	ns
LVDCI_18	0.47	0.50	0.60	1.99	2.15	2.35	2.62	2.91	3.17	ns

Input/Output Logic Switching Characteristics

Table 55: **ILOGIC Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Setup/Hold					
T_{ICE1CK}/T_{ICKCE1}	CE1 pin setup/hold with respect to CLK	0.42/0.00	0.48/0.00	0.67/0.00	ns
T_{ISRCK}/T_{ICKSR}	SR pin setup/hold with respect to CLK	0.53/0.01	0.61/0.01	0.99/0.01	ns
$T_{IDOCKE2}/T_{IOCKDE2}$	D pin setup/hold with respect to CLK without delay (HP I/O banks only)	0.01/0.27	0.01/0.29	0.01/0.34	ns
$T_{IDOCKDE2}/T_{IOCKDDE2}$	DDLY pin setup/hold with respect to CLK (using IDELAY) (HP I/O banks only)	0.01/0.27	0.02/0.29	0.02/0.34	ns
$T_{IDOCKE3}/T_{IOCKDE3}$	D pin setup/hold with respect to CLK without delay (HR I/O banks only)	0.01/0.27	0.01/0.29	0.01/0.34	ns
$T_{IDOCKDE3}/T_{IOCKDDE3}$	DDLY pin setup/hold with respect to CLK (using IDELAY) (HR I/O banks only)	0.01/0.27	0.02/0.29	0.02/0.34	ns
Combinatorial					
T_{IDIE2}	D pin to O pin propagation delay, no delay (HP I/O banks only)	0.09	0.10	0.12	ns
T_{IDIDE2}	DDLY pin to O pin propagation delay (using IDELAY) (HP I/O banks only)	0.10	0.11	0.13	ns
T_{IDIE3}	D pin to O pin propagation delay, no delay (HR I/O banks only)	0.09	0.10	0.12	ns
T_{IDIDE3}	DDLY pin to O pin propagation delay (using IDELAY) (HR I/O banks only)	0.10	0.11	0.13	ns
Sequential Delays					
T_{IDLOE2}	D pin to Q1 pin using flip-flop as a latch without delay (HP I/O banks only)	0.36	0.39	0.45	ns
$T_{IDLODE2}$	DDLY pin to Q1 pin using flip-flop as a latch (using IDELAY) (HP I/O banks only)	0.36	0.39	0.45	ns
T_{IDLOE3}	D pin to Q1 pin using flip-flop as a latch without delay (HR I/O banks only)	0.36	0.39	0.45	ns
$T_{IDLODE3}$	DDLY pin to Q1 pin using flip-flop as a latch (using IDELAY) (HR I/O banks only)	0.36	0.39	0.45	ns
T_{ICKQ}	CLK to Q outputs	0.47	0.50	0.58	ns
$T_{RQ\_ILOGICE2}$	SR pin to OQ/TQ out (HP I/O banks only)	0.84	0.94	1.16	ns
$T_{GSRQ\_ILOGICE2}$	Global set/reset to Q outputs (HP I/O banks only)	7.60	7.60	10.51	ns
$T_{RQ\_ILOGICE3}$	SR pin to OQ/TQ out (HR I/O banks only)	0.84	0.94	1.16	ns
$T_{GSRQ\_ILOGICE3}$	Global set/reset to Q outputs (HR I/O banks only)	7.60	7.60	10.51	ns
Set/Reset					
$T_{RPW\_ILOGICE2}$	Minimum pulse width, SR inputs (HP I/O banks only)	0.54	0.63	0.63	ns, Min
$T_{RPW\_ILOGICE3}$	Minimum pulse width, SR inputs (HR I/O banks only)	0.54	0.63	0.63	ns, Min

Table 60: **IO_FIFO Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
IO_FIFO Clock to Out Delays					
T_{OFFCKO_DO}	RDCLK to Q outputs	0.51	0.56	0.63	ns
T_{CKO_FLAGS}	Clock to IO_FIFO flags	0.59	0.62	0.81	ns
Setup/Hold					
T_{CCK_D}/T_{CKC_D}	D inputs to WRCLK	0.43/–0.01	0.47/–0.01	0.53/–0.01	ns
$T_{IFFCCK\_WREN}/T_{IFFCKC\_WREN}$	WREN to WRCLK	0.39/–0.01	0.43/–0.01	0.50/–0.01	ns
$T_{OFFCCK\_RDEN}/T_{OFFCKC\_RDEN}$	RDEN to RDCLK	0.49/0.01	0.53/0.02	0.61/0.02	ns
Minimum Pulse Width					
$T_{PWH\_IO\_FIFO}$	RESET, RDCLK, WRCLK	0.81	0.92	1.08	ns
$T_{PWL\_IO\_FIFO}$	RESET, RDCLK, WRCLK	0.81	0.92	1.08	ns
Maximum Frequency					
F_{MAX}	RDCLK and WRCLK	533.05	470.37	400.00	MHz

Table 64: **Block RAM and FIFO Switching Characteristics *(Cont'd)***

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Reset Delays					
T_{RCO_FLAGS}	Reset RST to FIFO flags/pointers(10)	0.76	0.83	0.93	ns, Max
$T_{RREC\_RST}/T_{RREM\_RST}$	FIFO reset recovery and removal timing(11)	1.59/–0.68	1.76/–0.68	2.01/–0.68	ns, Max
Maximum Frequency					
$F_{MAX\_BRAM\_WF\_NC}$	Block RAM (Write first and No change modes) When not in SDP RF mode	601.32	543.77	458.09	MHz
$F_{MAX\_BRAM\_RF\_PERFORMANCE}$	Block RAM (Read first, Performance mode) When in SDP RF mode but no address overlap between port A and port B	601.32	543.77	458.09	MHz
$F_{MAX\_BRAM\_RF\_DELAYED\_WRITE}$	Block RAM (Read first, Delayed_write mode) When in SDP RF mode and there is possibility of overlap between port A and port B addresses	528.26	477.33	400.80	MHz
$F_{MAX\_CAS\_WF\_NC}$	Block RAM Cascade (Write first, No change mode) When cascade but not in RF mode	551.27	493.93	408.00	MHz
$F_{MAX\_CAS\_RF\_PERFORMANCE}$	Block RAM Cascade (Read first, Performance mode) When in cascade with RF mode and no possibility of address overlap/one port is disabled	551.27	493.93	408.00	MHz
$F_{MAX\_CAS\_RF\_DELAYED\_WRITE}$	When in cascade RF mode and there is a possibility of address overlap between port A and port B	478.24	427.35	350.88	MHz
F_{MAX_FIFO}	FIFO in all modes without ECC	601.32	543.77	458.09	MHz
F_{MAX_ECC}	Block RAM and FIFO in ECC configuration	484.26	430.85	351.12	MHz

Notes:

1. TRACE will report all of these parameters as T_{RCKO_DO}.
2. T_{RCKO_DOR} includes T_{RCKO_DOW}, T_{RCKO_DOPR}, and T_{RCKO_DOPW} as well as the B port equivalent timing parameters.
3. These parameters also apply to synchronous FIFO with DO_REG = 0.
4. T_{RCKO_DO} includes T_{RCKO_DOP} as well as the B port equivalent timing parameters.
5. These parameters also apply to multirate (asynchronous) and synchronous FIFO with DO_REG = 1.
6. T_{RCKO_FLAGS} includes the following parameters: T_{RCKO_AEMPTY}, T_{RCKO_AFULL}, T_{RCKO_EMPTY}, T_{RCKO_FULL}, T_{RCKO_RDERR}, T_{RCKO_WRERR}.
7. $T_{RCKO\_POINTERS}$ includes both $T_{RCKO\_RDCOUNT}$ and $T_{RCKO\_WRCOUNT}$.
8. The ADDR setup and hold must be met when EN is asserted (even when WE is deasserted). Otherwise, block RAM data corruption is possible.
9. These parameters include both A and B inputs as well as the parity inputs of A and B.
10. T_{RCO_FLAGS} includes the following flags: AEMPTY, AFULL, EMPTY, FULL, RDERR, WRERR, RDCOUNT, and WRCOUNT.
11. RDEN and WREN must be held Low prior to and during reset. The FIFO reset must be asserted for at least five positive clock edges of the slowest clock (WRCLK or RDCLK).

Table 65: **DSP48E1 Switching Characteristics *(Cont'd)***

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Combinatorial Delays from Input Pins to Cascading Output Pins					
$T_{DSPDO\_\{A; B\}\_\{ACOUT; BCOUT\}}$	{A, B} input to {ACOUT, BCOUT} output	0.47	0.53	0.63	ns
$T_{DSPDO\_\{A, B\}\_CARRYCASCOUT\_MULT}$	{A, B} input to CARRYCASCOUT output using multiplier	3.44	3.94	4.69	ns
$T_{DSPDO\_D\_CARRYCASCOUT\_MULT}$	D input to CARRYCASCOUT output using multiplier	3.36	3.85	4.58	ns
$T_{DSPDO\_\{A, B\}\_CARRYCASCOUT}$	{A, B} input to CARRYCASCOUT output not using multiplier	1.50	1.72	2.04	ns
$T_{DSPDO\_C\_CARRYCASCOUT}$	C input to CARRYCASCOUT output	1.34	1.53	1.83	ns
Combinatorial Delays from Cascading Input Pins to All Output Pins					
$T_{DSPDO\_ACIN\_P\_MULT}$	ACIN input to P output using multiplier	3.09	3.55	4.24	ns
$T_{DSPDO\_ACIN\_P}$	ACIN input to P output not using multiplier	1.16	1.33	1.59	ns
$T_{DSPDO\_ACIN\_ACOUT}$	ACIN input to ACOUT output	0.32	0.37	0.45	ns
$T_{DSPDO\_ACIN\_CARRYCASCOUT\_MULT}$	ACIN input to CARRYCASCOUT output using multiplier	3.30	3.79	4.52	ns
$T_{DSPDO\_ACIN\_CARRYCASCOUT}$	ACIN input to CARRYCASCOUT output not using multiplier	1.37	1.57	1.87	ns
$T_{DSPDO\_PCIN\_P}$	PCIN input to P output	0.94	1.08	1.29	ns
$T_{DSPDO\_PCIN\_CARRYCASCOUT}$	PCIN input to CARRYCASCOUT output	1.15	1.32	1.57	ns
Clock to Outs from Output Register Clock to Output Pins					
$T_{DSPCKO\_P\_PREG}$	CLK PREG to P output	0.33	0.35	0.39	ns
$T_{DSPCKO\_CARRYCASCOUT\_PREG}$	CLK PREG to CARRYCASCOUT output	0.44	0.50	0.59	ns
Clock to Outs from Pipeline Register Clock to Output Pins					
$T_{DSPCKO\_P\_MREG}$	CLK MREG to P output	1.42	1.64	1.96	ns
$T_{DSPCKO\_CARRYCASCOUT\_MREG}$	CLK MREG to CARRYCASCOUT output	1.63	1.87	2.24	ns
$T_{DSPCKO\_P\_ADREG\_MULT}$	CLK ADREG to P output using multiplier	2.30	2.63	3.13	ns
$T_{DSPCKO\_CARRYCASCOUT\_ADREG\_MULT}$	CLK ADREG to CARRYCASCOUT output using multiplier	2.51	2.87	3.41	ns
Clock to Outs from Input Register Clock to Output Pins					
$T_{DSPCKO\_P\_AREG\_MULT}$	CLK AREG to P output using multiplier	3.34	3.83	4.55	ns
$T_{DSPCKO\_P\_BREG}$	CLK BREG to P output not using multiplier	1.39	1.59	1.88	ns
$T_{DSPCKO\_P\_CREG}$	CLK CREG to P output not using multiplier	1.43	1.64	1.95	ns
$T_{DSPCKO\_P\_DREG\_MULT}$	CLK DREG to P output using multiplier	3.32	3.80	4.51	ns

Clock Buffers and Networks

Table 66: **Global Clock Switching Characteristics (Including BUFGCTRL)**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
$T_{BCCCK\_CE}/T_{BCCKC\_CE}$(1)	CE pins setup/hold	0.12/0.30	0.14/0.38	0.26/0.38	ns
T_{BCCCK_S}/T_{BCCKC_S}(1)	S pins setup/hold	0.12/0.30	0.14/0.38	0.26/0.38	ns
T_{BCCKO_O}(2)	BUFGCTRL delay from I0/I1 to O	0.08	0.10	0.12	ns
Maximum Frequency					
F_{MAX_BUFG}	Global clock tree (BUFG)	741.00	710.00	625.00	MHz

Notes:

1. T_{BCCCK_CE} and T_{BCCKC_CE} must be satisfied to assure glitch-free operation of the global clock when switching between clocks. These parameters do not apply to the BUFGMUX primitive that assures glitch-free operation. The other global clock setup and hold times are optional; only needing to be satisfied if device operation requires simulation matches on a cycle-for-cycle basis when switching between clocks.
2. T_{BGCKO_O} (BUFG delay from I0 to O) values are the same as T_{BCCKO_O} values.

Table 67: **Input/Output Clock Switching Characteristics (BUFIO)**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
T_{BIOCKO_O}	Clock to out delay from I to O	1.04	1.14	1.32	ns
Maximum Frequency					
F_{MAX_BUFIO}	I/O clock tree (BUFIO)	800.00	800.00	710.00	MHz

Table 68: **Regional Clock Buffer Switching Characteristics (BUFR)**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
T_{BRCKO_O}	Clock to out delay from I to O	0.60	0.65	0.77	ns
$T_{BRCKO\_O\_BYP}$	Clock to out delay from I to O with Divide Bypass attribute set	0.30	0.32	0.38	ns
T_{BRDO_O}	Propagation delay from CLR to O	0.71	0.75	0.96	ns
Maximum Frequency					
F_{MAX_BUFR}(1)	Regional clock tree (BUFR)	600.00	540.00	450.00	MHz

Notes:

1. The maximum input frequency to the BUFR and BUFMR is the BUFIO F_{MAX} frequency.

Table 69: **Horizontal Clock Buffer Switching Characteristics (BUFH)**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
T_{BHCKO_O}	BUFH delay from I to O	0.10	0.11	0.13	ns
$T_{BHCCK\_CE}/T_{BHCKC\_CE}$	CE pin setup and hold	0.20/0.16	0.23/0.20	0.38/0.21	ns
Maximum Frequency					
F_{MAX_BUFH}	Horizontal clock buffer (BUFH)	741.00	710.00	625.00	MHz

Device Pin-to-Pin Output Parameter Guidelines

Table 73: **Clock-Capable Clock Input to Output Delay Without MMCM/PLL (Near Clock Region)**

Symbol	Description	Device	Speed Grade			Units
			-3	-2	-1	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flops, Fast Slew Rate, *without* MMCM/PLL.						
T_{ICKOF}	Clock-capable clock input and OUTFF *without* MMCM/PLL (near clock region)	XC7Z030	5.32	5.85	6.55	ns
		XC7Z045	5.27	5.78	6.48	ns
		XC7Z100				ns

Notes:

1. This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

Table 74: **Clock-Capable Clock Input to Output Delay Without MMCM/PLL (Far Clock Region)**

Symbol	Description	Device	Speed Grade			Units
			-3	-2	-1	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flops, Fast Slew Rate, *without* MMCM/PLL.						
$T_{ICKOFFAR}$	Clock-capable clock input and OUTFF *without* MMCM/PLL (far clock region)	XC7Z030	5.32	5.85	6.55	ns
		XC7Z045	5.88	6.46	7.23	ns
		XC7Z100				ns

Notes:

1. This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

Table 75: **Clock-Capable Clock Input to Output Delay With MMCM**

Symbol	Description	Device	Speed Grade			Units
			-3	-2	-1	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flops, Fast Slew Rate, *with* MMCM.						
$T_{ICKOFMMCMCC}$	Clock-capable clock input and OUTFF *with* MMCM	XC7Z030	0.92	0.92	0.92	ns
		XC7Z045	0.97	0.97	0.97	ns
		XC7Z100				ns

Notes:

1. This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
2. MMCM output jitter is already included in the timing calculation.

Table 76: **Clock-Capable Clock Input to Output Delay With PLL**

Symbol	Description	Device	Speed Grade			Units
			-3	-2	-1	
SSTL15 Clock-Capable Clock Input to Output Delay using Output Flip-Flops, Fast Slew Rate, *with* PLL.						
$T_{ICKOFPLLCC}$	Clock-capable clock input and OUTFF *with* PLL	XC7Z030	0.81	0.81	0.81	ns
		XC7Z045	0.86	0.86	0.86	ns
		XC7Z100				ns

Notes:

1. This table lists representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
2. PLL output jitter is already included in the timing calculation.

Table 91: **GTX Transceiver Transmitter Switching Characteristics *(Cont'd)***

Symbol	Description	Condition	Min	Typ	Max	Units
$TJ_{6.6\_CPLL}$	Total jitter(3)(4)	6.6 Gb/s	–	–	0.30	UI
$DJ_{6.6\_CPLL}$	Deterministic jitter(3)(4)		–	–	0.15	UI
$TJ_{5.0}$	Total jitter(3)(4)	5.0 Gb/s	–	–	0.33	UI
$DJ_{5.0}$	Deterministic jitter(3)(4)		–	–	0.15	UI
$TJ_{4.25}$	Total jitter(3)(4)	4.25 Gb/s	–	–	0.33	UI
$DJ_{4.25}$	Deterministic jitter(3)(4)		–	–	0.14	UI
$TJ_{3.75}$	Total jitter(3)(4)	3.75 Gb/s	–	–	0.34	UI
$DJ_{3.75}$	Deterministic jitter(3)(4)		–	–	0.16	UI
$TJ_{3.2}$	Total jitter(3)(4)	3.20 Gb/s(5)	–	–	0.2	UI
$DJ_{3.2}$	Deterministic jitter(3)(4)		–	–	0.1	UI
$TJ_{3.2L}$	Total jitter(3)(4)	3.20 Gb/s(6)	–	–	0.35	UI
$DJ_{3.2L}$	Deterministic jitter(3)(4)		–	–	0.16	UI
$TJ_{2.5}$	Total jitter(3)(4)	2.5 Gb/s(7)	–	–	0.20	UI
$DJ_{2.5}$	Deterministic jitter(3)(4)		–	–	0.08	UI
$TJ_{1.25}$	Total jitter(3)(4)	1.25 Gb/s(8)	–	–	0.15	UI
$DJ_{1.25}$	Deterministic jitter(3)(4)		–	–	0.06	UI
TJ_{500}	Total jitter(3)(4)	500 Mb/s	–	–	0.1	UI
DJ_{500}	Deterministic jitter(3)(4)		–	–	0.03	UI

Notes:

1. Using same REFCLK input with TX phase alignment enabled for up to 12 consecutive transmitters (three fully populated GTX Quads).
2. Using QPLL_FBDIV = 40, 20-bit internal data width. These values are NOT intended for protocol specific compliance determinations.
3. Using CPLL_FBDIV = 2, 20-bit internal data width. These values are NOT intended for protocol specific compliance determinations.
4. All jitter values are based on a bit-error ratio of $1e^{-12}$.
5. CPLL frequency at 3.2 GHz and TXOUT_DIV = 2.
6. CPLL frequency at 1.6 GHz and TXOUT_DIV = 1.
7. CPLL frequency at 2.5 GHz and TXOUT_DIV = 2.
8. CPLL frequency at 2.5 GHz and TXOUT_DIV = 4.

Table 96: **CEI-6G and CEI-11G Protocol Characteristics**

Description	Line Rate (Mb/s)	Interface	Min	Max	Units
CEI-6G Transmitter Jitter Generation					
Total transmitter jitter(1)	4976–6375	CEI-6G-SR	–	0.3	UI
		CEI-6G-LR	–	0.3	UI
CEI-6G Receiver High Frequency Jitter Tolerance					
Total receiver jitter tolerance(1)	4976–6375	CEI-6G-SR	0.6	–	UI
		CEI-6G-LR	0.95	–	UI
CEI-11G Transmitter Jitter Generation					
Total transmitter jitter(2)	9950–11100	CEI-11G-SR	–	0.3	UI
		CEI-11G-LR/MR	–	0.3	UI
CEI-11G Receiver High Frequency Jitter Tolerance					
Total receiver jitter tolerance(2)	9950–11100	CEI-11G-SR	0.65	–	UI
		CEI-11G-MR	0.65	–	UI
		CEI-11G-LR	0.825	–	UI

Notes:

1. Tested at most commonly used line rate of 6250 Mb/s using 390.625 MHz reference clock.
2. Tested at line rate of 9950 Mb/s using 155.46875 MHz reference clock and 11100 Mb/s using 173.4375 MHz reference clock.

Table 97: **SFP+ Protocol Characteristics**

Description	Line Rate (Mb/s)	Min	Max	Units
SFP+ Transmitter Jitter Generation				
Total transmitter jitter	9830.40(1)	–	0.28	UI
	9953.00			
	10312.50			
	10518.75			
	11100.00			
SFP+ Receiver Frequency Jitter Tolerance				
Total receiver jitter tolerance	9830.40(1)	0.7	–	UI
	9953.00			
	10312.50			
	10518.75			
	11100.00			

Notes:

1. Line rated used for CPRI over SFP+ applications.

Table 98: **CPRI Protocol Characteristics**

Description	Line Rate (Mb/s)	Min	Max	Units
CPRI Transmitter Jitter Generation				
Total transmitter jitter	614.4	–	0.35	UI
	1228.8	–	0.35	UI
	2457.6	–	0.35	UI
	3072.0	–	0.35	UI
	4915.2	–	0.3	UI
	6144.0	–	0.3	UI
	9830.4	–	Note 1	UI
CPRI Receiver Frequency Jitter Tolerance				
Total receiver jitter tolerance	614.4	0.65	–	UI
	1228.8	0.65	–	UI
	2457.6	0.65	–	UI
	3072.0	0.65	–	UI
	4915.2	0.95	–	UI
	6144.0	0.95	–	UI
	9830.4	Note 1	–	UI

Notes:

1. Tested per SFP+ specification, see Table 97.

Integrated Interface Block for PCI Express Designs Switching Characteristics

More information and documentation on solutions for PCI Express designs can be found at:
http://www.xilinx.com/technology/protocols/pciexpress.htm

Table 99: **Maximum Performance for PCI Express Designs**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
$F_{PIPECLK}$	Pipe clock maximum frequency	250	250	250	MHz
$F_{USERCLK}$	User clock maximum frequency	500	500	250	MHz
$F_{USERCLK2}$	User clock 2 maximum frequency	250	250	250	MHz
F_{DRPCLK}	DRP clock maximum frequency	250	250	250	MHz